

LM3089 FM Receiver IF System

General Description

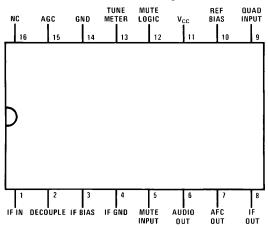
The LM3089 has been designed to provide all the major functions required for modern FM IF designs of automotive, high-fidelity and communications receivers.

Features

- \blacksquare Three stage IF amplifier/limiter provides 12 μV (typ) -3 dB limiting sensitivity
- Balanced product detector and audio amplifier provide 400 mV (typ) of recovered audio with distortion as low as 0.1% with proper external coil designs.
- Four internal carrier level detectors provide delayed AGC signal to tuner, IF level meter drive current and interchannel mute control
- AFC amplifier provides AFC current for tuner and/or center tuning meters
- Improved operating and temperature performance, especially when using high Q quadrature coils in narrow band FM communications receivers
- No mute circuit latchup problems
- A direct replacement for CA3089E

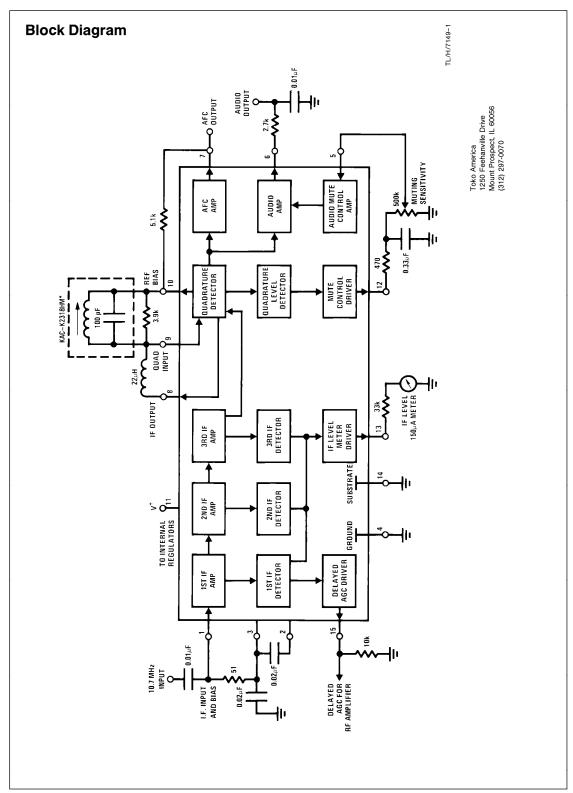
Connection Diagram

Dual-In-Line Package



TI /H/7149-2

Top View
Order Number LM3089N
See NS Package Number N16E



Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage Between Pin 11 and Pins 4, 14 + 16V
DC Current Out of Pin 12 5 mA
DC Current Out of Pin 13 5 mA
DC Current Out of Pin 15 2 mA

Power Dissipation (Note 2) 1500 mW Operating Temperature Range -40°C to $+85^{\circ}\text{C}$ Storage Temperature Range -65°C to $+150^{\circ}\text{C}$ Lead Temperature (Soldering, 10 seconds) 260°C

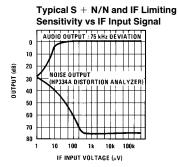
Electrical Characteristics (T_A = 25°C, V_{CC} = +12V, see Test Circuit)

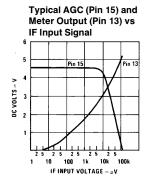
Symbol	Parameter	Conditions	Min	Тур	Max	Units
DC CHARA	CTERISTICS (V _{IN} = 0, NOT MU	TED)		•		
I ₁₁	Supply Current		16	23	30	mA
V1, 2, 3	IF Input and Bias		1.2	1.9	2.4	V
V6	Audio Output		5.0	5.6	6.0	V
V7	AFC Output		5.0	5.6	6.0	V
V10	Reference Bias		5.0	5.6	6.0	V
V12	Mute Control		5.0	5.4	6.0	V
V13	IF Level			0	0.5	V
V15	Delayed AGC		4.2	4.7	5.3	V
DYNAMIC (CHARACTERISTICS f _o = 10.7 M	NHZ, $\Delta f = \pm 75$ kHz @ 400 Hz				
V _{IN} (LIM)	Input Limiting -3 dB			12	25	μ٧
AMR	AM Rejection	$V_{IN} = 100 \text{ mV}, AM: 30\%$	45	55		−dB
V _O (AF)	Recovered Audio	$V_{IN} = 10 \text{ mV}$	300	400	500	mVrms
THD	Total Harmonic Distortion					
	Single Tuned (Note 1)	$V_{IN} = 100 \text{ mV}$		0.5	1.0	%
	Double Tuned (Note 1)	$V_{IN} = 100 \text{ mV}$		0.1	0.3	%
S+N/N	Signal to Noise Ratio	V _{IN} = 100 mV	60	70		dB
V12	Mute Control	V _{IN} = 100 mV		0	0.5	V
V13	IF Level	V _{IN} = 100 mV	4.0	5.0	6.0	V
V13	IF Level	$V_{IN} = 500 \mu V$	1.0	1.5	2.0	V
V15	Delayed AGC	$V_{IN} = 100 \text{ mV}$		0.1	0.5	V
V15	Delayed AGC	$V_{IN} = 30 \text{ mV}$		2.5		V
V _O (AF)	Audio Muted	$V_{IN} = 100 \text{ mV}, V5 = +2.5V$		60		-dB

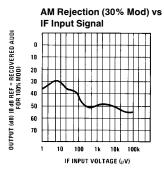
Note 1: Distortion is a function of quadrature coil used.

Note 2: For operation in ambient temperatures above 25°C, the device must be derated based on a 150°C maximum junction temperature and a thermal resistance of 80°C/W junction to ambient.

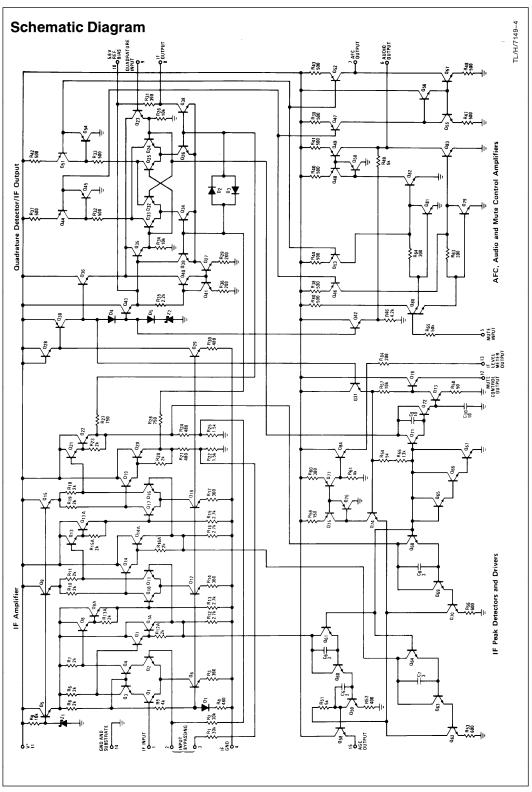
Typical Performance Characteristics



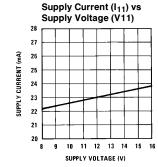


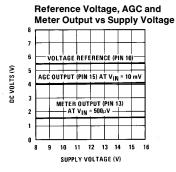


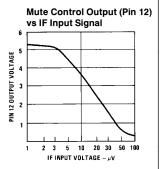
TL/H/7149-3



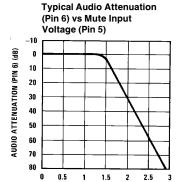
Typical Performance Characteristics



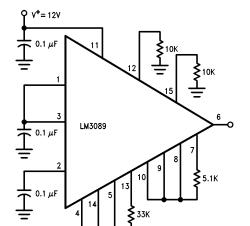




TL/H/7149-5



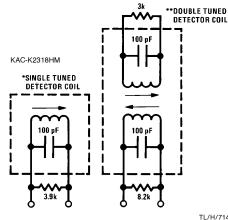
MUTE INPUT VOLTAGE (PIN 5) (V) TL/H/7149-6



DC Test Circuit

TL/H/7149-7

AC Test Circuit



*For single tuned dectector coil: L_O tunes with 100 pF at 10.7 MHz

 Q_{UL} (unloaded) $\simeq 75$ Q_{L} (loaded) $\simeq 13$ for V9 $\simeq 150$ mVrms

**For double tuned detector coil:

 $Q_{ULPRI} = Q_{ULSEC} \cong 75$ kQ $\cong 0.7$ for V9 $\cong 150$ mVrms

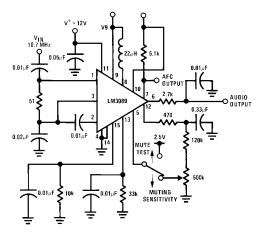
Note:

The recovered audio output voltage will be approximately 0.5 dB less when using the double tuned detector coil.

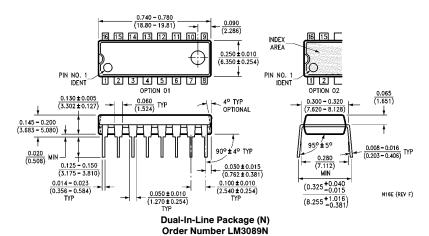
For proper operation of the mute circuit, the RF voltage at pin 9 should be 150 mVrms \pm 30 mV.

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AC Test Circuit (Continued)



Physical Dimensions inches (millimeters)



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See NS Package Number N16E

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- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

TI /H/7149-9



National Semiconductor National Semiconducto Corporation 1111 West Bardin Road Arlington, TX 76017 Tel: 1(800) 272-9959 Fax: 1(800) 737-7018

National Semiconductor Europe

Fax: (+49) 0-180-530 85 86 Fax: (+49) U-18U-35U oo oo Email: onjwege etevm2.nsc.com Deutsch Tel: (+49) 0-180-530 85 85 English Tei: (+49) 0-180-532 78 32 Français Tel: (+49) 0-180-532 93 58 Italiano Tel: (+49) 0-180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.

Tsimshatsui, Kowloon Hong Kong Tel: (852) 2737-1600 Fax: (852) 2736-9960

National Semiconductor

Japan Ltd.
Tel: 81-043-299-2309
Fax: 81-043-299-2408